

10G EPON ONU BOSA(10G1270nmTX 10G1577nmRX)

Features:

- Coaxial Package
- ◆ InGaAsP/InP MQW-DFB Laser Diode
- Low threshold, high slope efficiency and high output power
- ◆ Operating Case Temperature: 0°C to +70°C
- High channel isolation
- Low return loss
- Optional with Isolator

Applications:

- ♦ EPON ONU side
- Long distance digital transmission system
- Cable television system
- WDM systems

Absolute Maximum Ratings:

Parameter	Symbol	Min.	Max.	Unit
Storage Temperature	Tstg	-40	85	°C
Operating Case Temperature	Topr	0	70	°C
Reverse Voltage(LD)	V _{RL}		2	V
Reverse Voltage(PD)	V _{RD}		20	V
Photodiode Forward Current(PD)	I _{FD}		2	mA
LD Direct Forward Current	I _{FL}		120	mA
Lead Soldering (Temperature)/(Time)			260/10	°C/Sec



Electrical and Optical Characteristics – Transmitter:

Parameter	Symbol	Min.	Тур.	Max.	Unit	Note
Output Optical Power	Pf	2.5			mW	CW, lop=lth+20mA
Threshold Current	lth		8	15	mA	at Tc=25℃
Peak Wavelength	λр	1260	1270	1280	nm	Tc=25 ℃
Side Mode Suppression Ratio	SMSR	35	40		dB	CW,Tc=0~85 ℃
Operating Voltage	Vop		1.2	1.7	V	CW, lop=lth+20mA,
PD Monitor Current	Im	0.05		1.0	mA	CW, lop=lth+20mA,
Monitor Dark Current	ld			0.1	μA	V _{RD} =5V
Optical Isolation	lso	-30			dB	
Tracking Error	TE	-1.5		1.5	dB	lop=lth+20mA, 0℃/+25℃,+25℃/+70℃

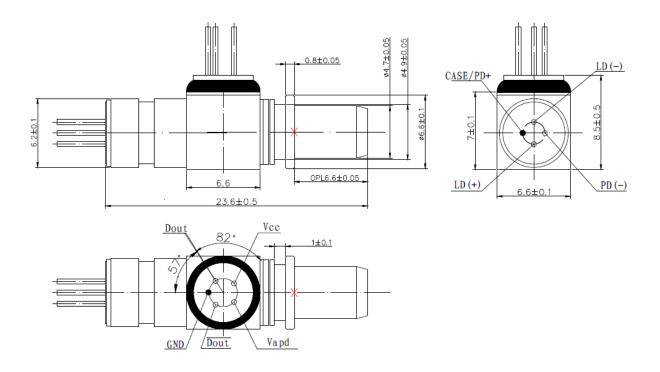
Electrical / Optical Specifications – Receiver:

Description	Symbol	Min.	Тур.	Max.	Unit	Note		
Operating Wavelength	λ	1575	1577	1580	nm			
Supply Voltage	Vcc	3.0	3.3	3.6	V			
Supply Current	lcc	40	55	70	mA			
Break-down Voltage	Vbr	25	34	40	V	ld=10µA		
APD Responsivity	R	0.65			A/W	M=1,V _R =10V		
Optical Isolation From	ISO	30			dB	λ= 1310/1490/1550nm		
External Source								
Optical Crosstalk From	Xopt		-45	-40	dB			
Internal Laser	,pr							

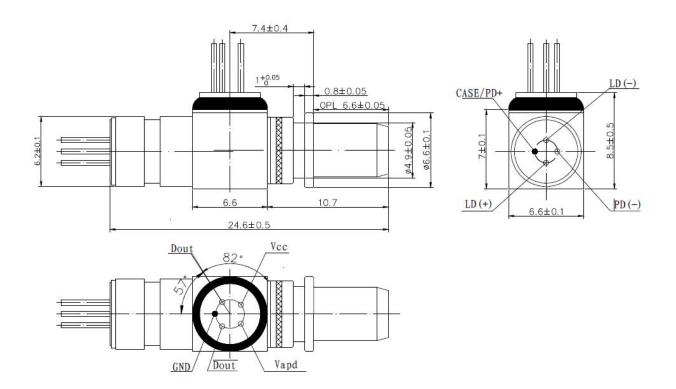


Package Dimension:

SC/PC receptacle (Non-electrical isolation)

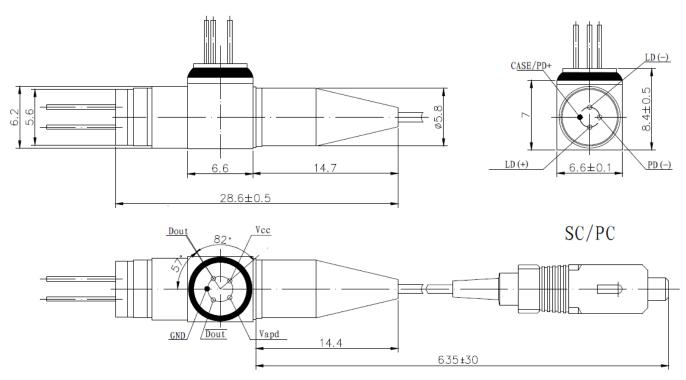


SC/PC receptacle (Electrical isolation)



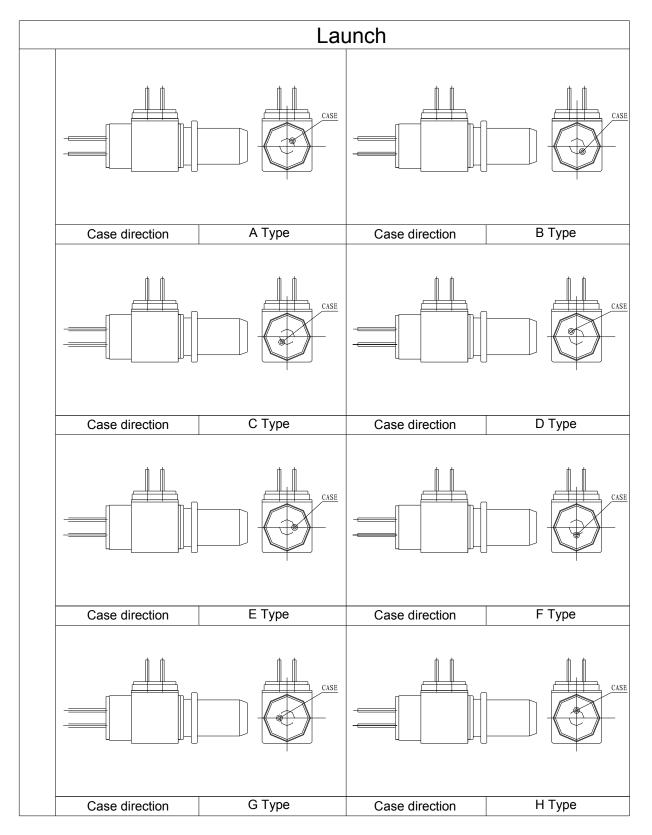


PBIDI-SC/PC:



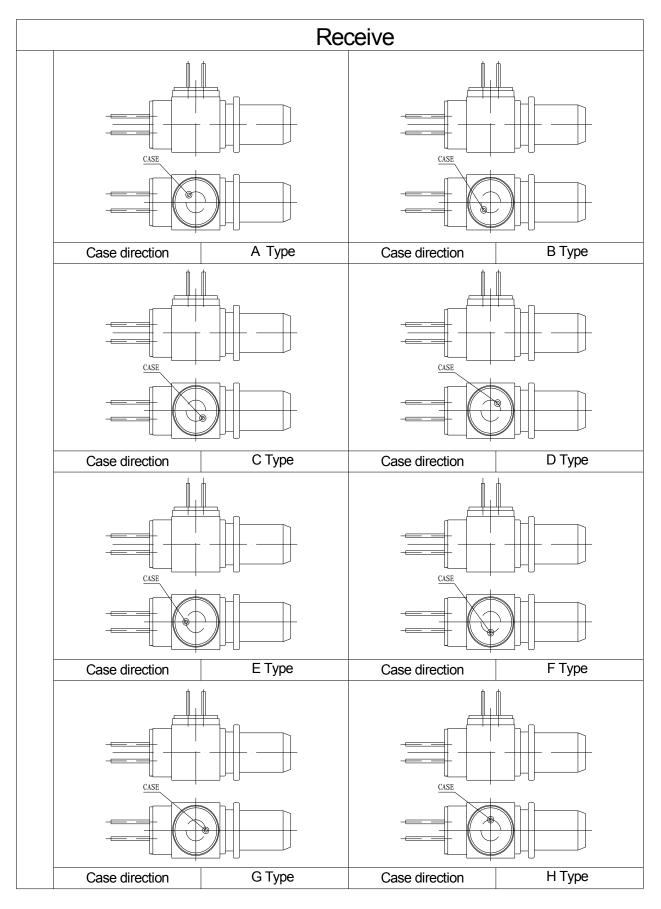


TX Pin Order Code:





RX Pin Order Code:





Nomenclature:

A B C D E F G H I J K

Code	Parameter	Detailed Description							
А	Laser Type	D=DFB LD							
В	Launch Wavelength	A=1270							
С	Launch Data rate	1=10G							
D	Output Power	20=2.0~2.99mW							
Е	Receiver Wavelength	H=1577							
F	Receiver Data rate	T=10G							
G	Connector	SR= SC/PC receptacle			SP= SC/PC Pigtail				
Н	Connector Type	1= Non-electrical isolation			2= Electrical isolation				
I	TX Pin Package Direction	А	В	С	D	E	F	G	Н
J	RX Pin Package Direction	А	В	С	D	E	F	G	Н
К	Isolator	G=with I							

Precaution:

(1) The modules should be handled in the same manner as ordinary semiconductor devices to prevent the electro-static damages. For safe keeping and carrying, the modules should be packaged with ESD proof material. To assemble the modules on PCB, the workbench, the soldering iron and the human body should be grounded.

(2) Please pay special attention to the atmosphere condition because the dew on the module may cause some electrical damages.

(3) Under such a strong vibration environment as in automobile, the performance and reliability are not guaranteed.

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